

Pb Free Plating Product

MURF1605 thru MURF1660



16.0 Ampere Isolated Glass Passivated Ultra Fast Recovery Rectifier

Features

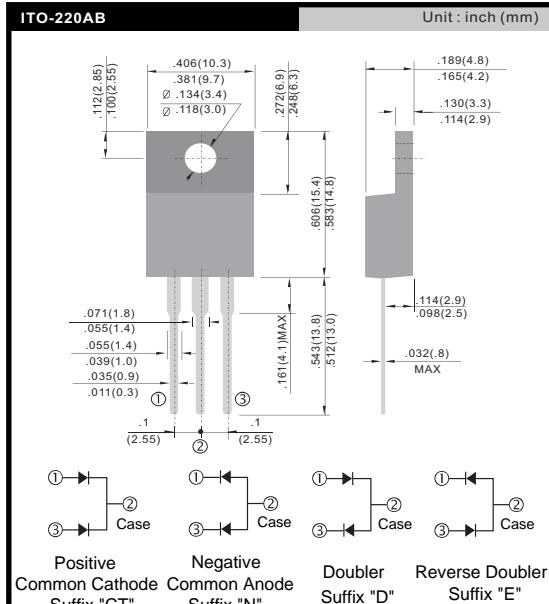
- ★ Fast switching for high efficiency
- ★ Low forward voltage drop
- ★ High current capability
- ★ Low reverse leakage current
- ★ High surge current capability

Application

- ★ Automotive Environment|DC Motor Control
- ★ Plating Power Supply|UPS
- ★ Amplifier and Sound Device System etc..

Mechanical Data

- ★ Case: Molded plastic Isolated/Insulated ITO-220AB
- ★ Epoxy: UL 94V-0 rate flame retardant
- ★ Terminals: Solderable per MIL-STD-202 method 208
- ★ Polarity: As marked on diode body
- ★ Mounting position: Any
- ★ Weight: 2.03 grams



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	SUFFIX "CT"	SYMBOL	MURF1605CT	MURF1610CT	MURF1620CT	MURF1630CT	MURF1640CT	MURF1660CT	UNIT
COMMON CATHODE POLARITY	SUFFIX "CT"		MURF1605CT	MURF1610CT	MURF1620CT	MURF1630CT	MURF1640CT	MURF1660CT	
COMMON ANODE POLARITY	SUFFIX "N"		MURF1605N	MURF1610N	MURF1620N	MURF1630N	MURF1640N	MURF1660N	
DOUBLER POLARITY	SUFFIX "D"		MURF1605D	MURF1610D	MURF1620D	MURF1630D	MURF1640D	MURF1660D	
REVERSE POLARITY	SUFFIX "E"		MURF1605E	MURF1610E	MURF1620E	MURF1630E	MURF1640E	MURF1660E	
Maximum Recurrent Peak Reverse Voltage	VRRM		50	100	200	300	400	600	V
Maximum RMS Voltage	VRMS		35	70	140	210	280	420	V
Maximum DC Blocking Voltage	VDC		50	100	200	300	400	600	V
Maximum Average Forward Rectified Current Tc=100°C	IF(AV)					16.0			A
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)	IFSM				175		150		A
Maximum Instantaneous Forward Voltage @ 8.0 A	VF			0.98		1.3		1.7	V
Maximum DC Reverse Current @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	IR				10.0 250				uA uA
Maximum Reverse Recovery Time (Note 1)	Tr				35				nS
Typical junction Capacitance (Note 2)	CJ				90				pF
Typical Thermal Resistance (Note 3)	R _{θJC}				2.2				°CW
Operating Junction and Storage Temperature Range	T _J , T _{STG}				-55 to + 150				°C

NOTES : (1) Reverse recovery test conditions IF= 0.5A, R= 1.0A, Irr = 0.25A.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

(3) Thermal Resistance junction to case.

FIG.1 - FORWARD CURRENT DERATING CURVE

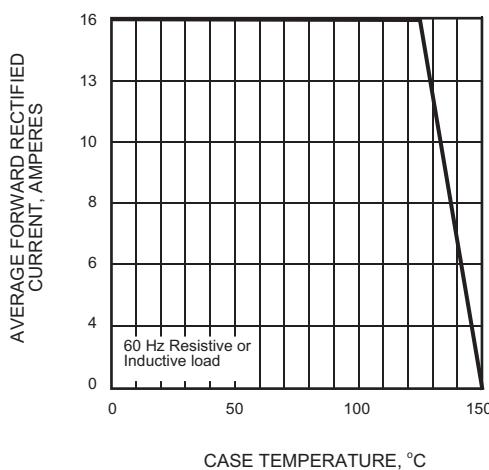


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

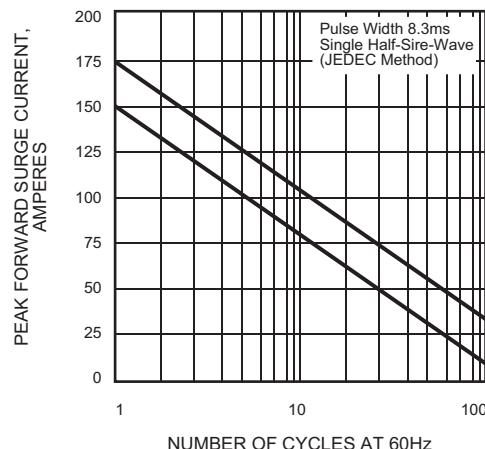


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

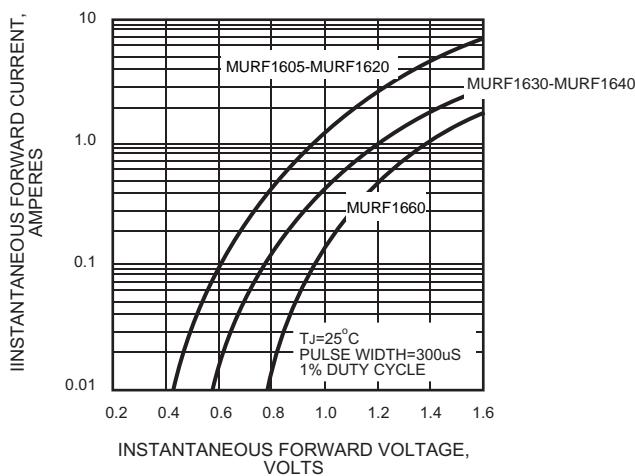


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

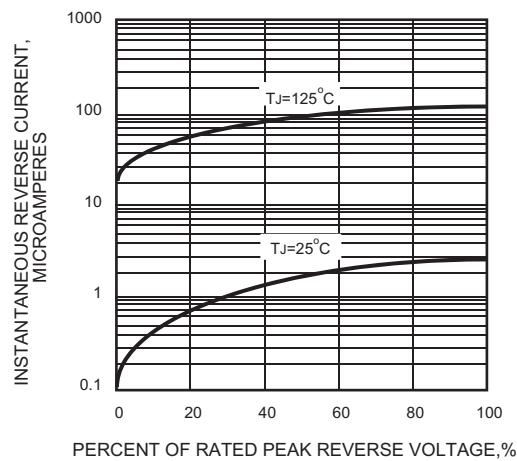


FIG.5 - TYPICAL JUNCTION CAPACITANCE

